

## High Efficiency SMT LEDs

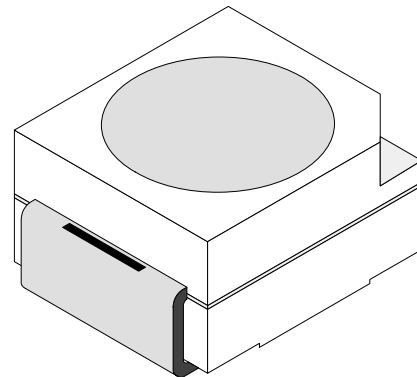
Color	Type	Technology	Angle of half intensity $\pm\varphi$
High efficiency red	TLMH3100	GaAsP on GaP	60°
Soft orange	TLMO3100	GaAsP on GaP	
Yellow	TLMY3100	GaAsP on GaP	
Green	TLMG3100	GaP on GaP	
Pure green	TLMP3100	GaP on GaP	

### Description

These devices have been designed to meet the increasing demand for surface mounting technology. The package of the TLM.310. is the PL-CC-2 (equivalent to a size B tantalum capacitor). It consists of a lead frame which is surrounded with a white thermoplast. The reflector inside this package is filled up with clear epoxy.

### Features

- SMT LEDs with exceptional brightness
- Luminous intensity categorized
- Compatible with automatic placement equipment
- EIA and ICE standard package
- Compatible with infrared, vapor phase and wave solder processes according to CECC
- Available in 8 mm tape
- Low profile package
- Non diffused lens: excellent for coupling to light pipes and backlighting
- Low power consumption
- Luminous intensity ratio in one packaging unit  
 $I_{Vmax}/I_{Vmin} \leq 2.0$



94 8553

### Applications

Automotive: backlighting in dashboards and switches  
Telecommunication: indicator and backlighting in telephone and fax  
Indicator and backlight for audio and video equipment

Indicator and backlight in office equipment  
Flat backlight for LCDs, switches and symbols  
General use

## TLM.310.

### Absolute Maximum Ratings

$T_{amb} = 25^{\circ}\text{C}$ , unless otherwise specified

**TLMH3100 , TLMO3100 , TLMY3100 , TLMG3100 , TLMP3100**

Parameter	Test Conditions	Symbol	Value	Unit
Reverse voltage		$V_R$	6	V
DC forward current	$T_{amb} \leq 60^{\circ}\text{C}$	$I_F$	30	mA
Surge forward current	$t_p \leq 10 \mu\text{s}$	$I_{FSM}$	0.5	A
Power dissipation	$T_{amb} \leq 60^{\circ}\text{C}$	$P_V$	100	mW
Junction temperature		$T_j$	100	$^{\circ}\text{C}$
Operating temperature range		$T_{amb}$	-40 to +100	$^{\circ}\text{C}$
Storage temperature range		$T_{stg}$	-55 to +100	$^{\circ}\text{C}$
Soldering temperature	$t \leq 5 \text{ s}$	$T_{sd}$	260	$^{\circ}\text{C}$
Thermal resistance junction/ambient	mounted on PC board (pad size > 16 mm <sup>2</sup> )	$R_{thJA}$	400	K/W

### Optical and Electrical Characteristics

$T_{amb} = 25^{\circ}\text{C}$ , unless otherwise specified

#### High efficiency red (TLMH3100)

Parameter	Test Conditions	Type	Symbol	Min	Typ	Max	Unit
Luminous intensity	$I_F = 10 \text{ mA}$		$I_V$	2.5	6		mcd
Dominant wavelength	$I_F = 10 \text{ mA}$		$\lambda_d$	612		625	nm
Peak wavelength	$I_F = 10 \text{ mA}$		$\lambda_p$		635		nm
Angle of half intensity	$I_F = 10 \text{ mA}$		$\phi$		$\pm 60$		deg
Forward voltage	$I_F = 20 \text{ mA}$		$V_F$		2.4	2.8	V
Reverse voltage	$I_R = 10 \mu\text{A}$		$V_R$	6	15		V
Junction capacitance	$V_R = 0, f = 1 \text{ MHz}$		$C_j$		15		pF

#### Soft orange (TLMO3100)

Parameter	Test Conditions	Type	Symbol	Min	Typ	Max	Unit
Luminous intensity	$I_F = 10 \text{ mA}$		$I_V$	2.5	8		mcd
Dominant wavelength	$I_F = 10 \text{ mA}$		$\lambda_d$	598		611	nm
Peak wavelength	$I_F = 10 \text{ mA}$		$\lambda_p$		605		nm
Angle of half intensity	$I_F = 10 \text{ mA}$		$\phi$		$\pm 60$		deg
Forward voltage	$I_F = 20 \text{ mA}$		$V_F$		2.4	3	V
Reverse voltage	$I_R = 10 \mu\text{A}$		$V_R$	6	15		V
Junction capacitance	$V_R = 0, f = 1 \text{ MHz}$		$C_j$		15		pF

**Yellow (TLMY3100)**

Parameter	Test Conditions	Type	Symbol	Min	Typ	Max	Unit
Luminous intensity	$I_F = 10 \text{ mA}$		$I_V$	2.5	6		mcd
Dominant wavelength	$I_F = 10 \text{ mA}$		$\lambda_d$	581		594	nm
Peak wavelength	$I_F = 10 \text{ mA}$		$\lambda_p$		585		nm
Angle of half intensity	$I_F = 10 \text{ mA}$		$\varphi$		$\pm 60$		deg
Forward voltage	$I_F = 20 \text{ mA}$		$V_F$		2.4	2.8	V
Reverse voltage	$I_R = 10 \mu\text{A}$		$V_R$	6	15		V
Junction capacitance	$V_R = 0, f = 1 \text{ MHz}$		$C_j$		15		pF

**Green (TLMG3100)**

Parameter	Test Conditions	Type	Symbol	Min	Typ	Max	Unit
Luminous intensity	$I_F = 10 \text{ mA}$		$I_V$	4	9		mcd
Dominant wavelength	$I_F = 10 \text{ mA}$		$\lambda_d$	562		575	nm
Peak wavelength	$I_F = 10 \text{ mA}$		$\lambda_p$		565		nm
Angle of half intensity	$I_F = 10 \text{ mA}$		$\varphi$		$\pm 60$		deg
Forward voltage	$I_F = 20 \text{ mA}$		$V_F$		2.4	2.8	V
Reverse voltage	$I_R = 10 \mu\text{A}$		$V_R$	6	15		V
Junction capacitance	$V_R = 0, f = 1 \text{ MHz}$		$C_j$		15		pF

**Pure green (TLMP3100)**

Parameter	Test Conditions	Type	Symbol	Min	Typ	Max	Unit
Luminous intensity	$I_F = 10 \text{ mA}$		$I_V$	1	4		mcd
Dominant wavelength	$I_F = 10 \text{ mA}$		$\lambda_d$	555		565	nm
Peak wavelength	$I_F = 10 \text{ mA}$		$\lambda_p$		555		nm
Angle of half intensity	$I_F = 10 \text{ mA}$		$\varphi$		$\pm 60$		deg
Forward voltage	$I_F = 20 \text{ mA}$		$V_F$		2.4	3	V
Reverse voltage	$I_R = 10 \mu\text{A}$		$V_R$	6	15		V
Junction capacitance	$V_R = 0, f = 1 \text{ MHz}$		$C_j$		15		pF

## Typical Characteristics ( $T_{amb} = 25^{\circ}\text{C}$ , unless otherwise specified)

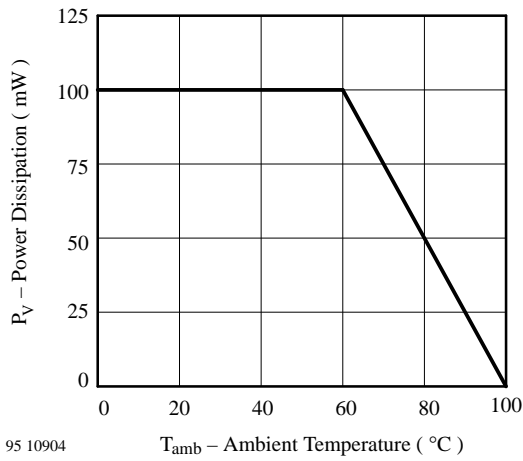


Figure 1. Power Dissipation vs. Ambient Temperature

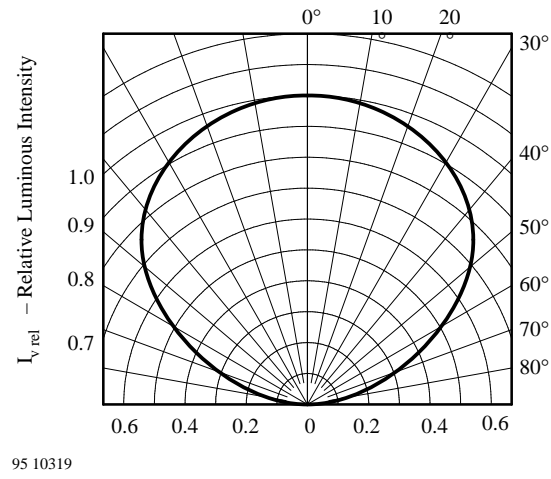


Figure 4. Rel. Luminous Intensity vs. Angular Displacement

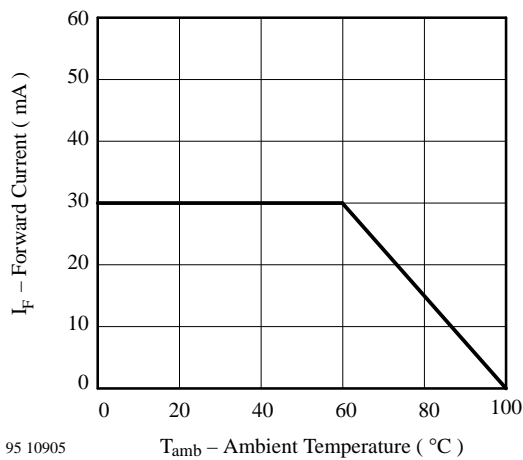


Figure 2. Forward Current vs. Ambient Temperature

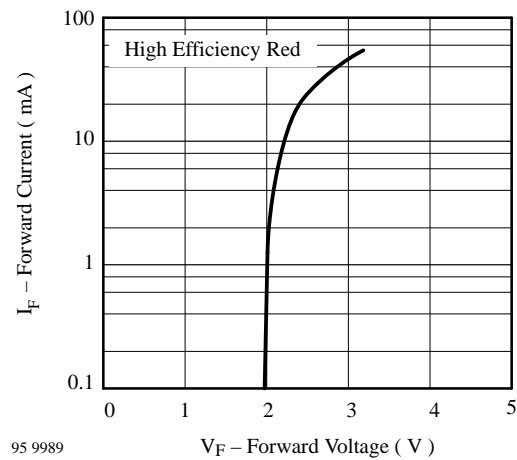


Figure 5. Forward Current vs. Forward Voltage

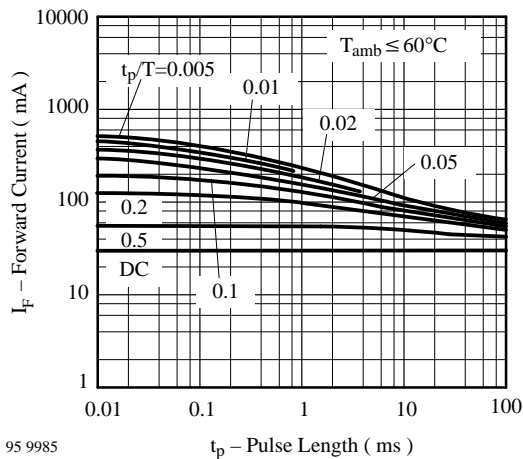


Figure 3. Forward Current vs. Pulse Length

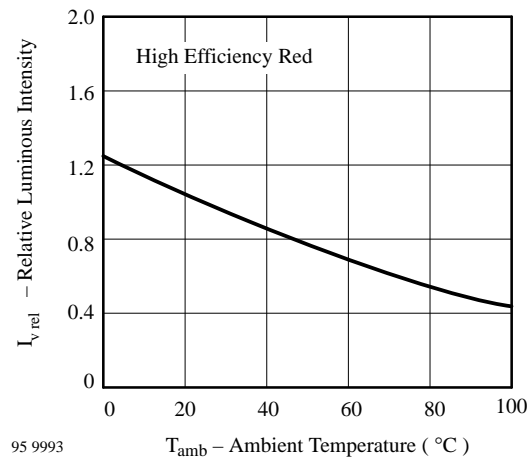


Figure 6. Rel. Luminous Intensity vs. Ambient Temperature

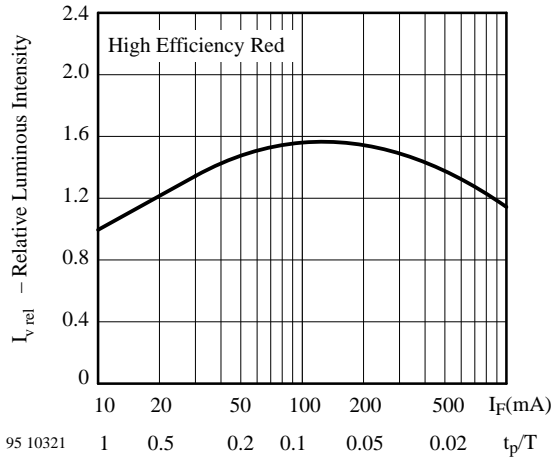


Figure 7. Rel. Lumin. Intensity vs. Forw. Current/Duty Cycle

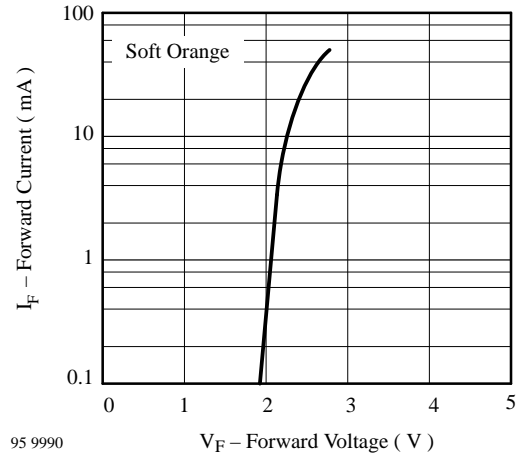


Figure 10. Forward Current vs. Forward Voltage

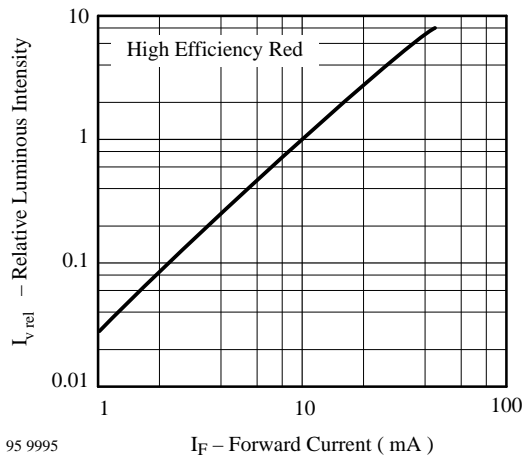


Figure 8. Relative Luminous Intensity vs. Forward Current

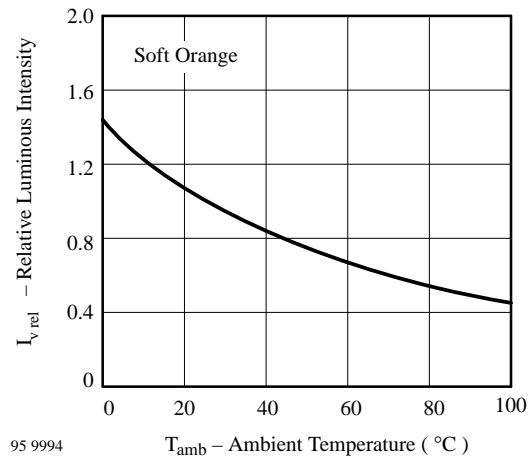


Figure 11. Rel. Luminous Intensity vs. Ambient Temperature

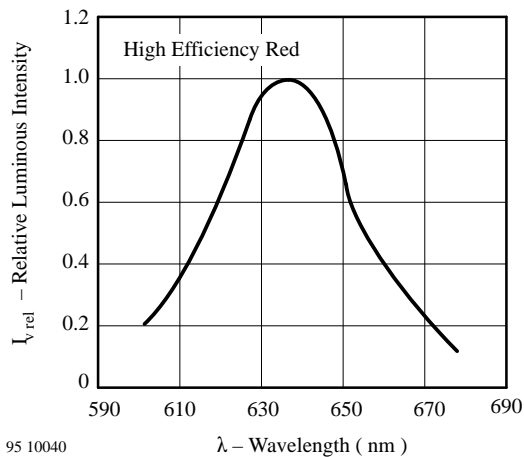


Figure 9. Relative Luminous Intensity vs. Wavelength

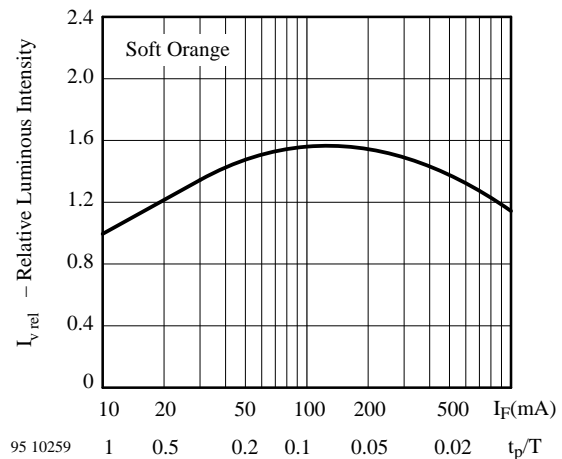
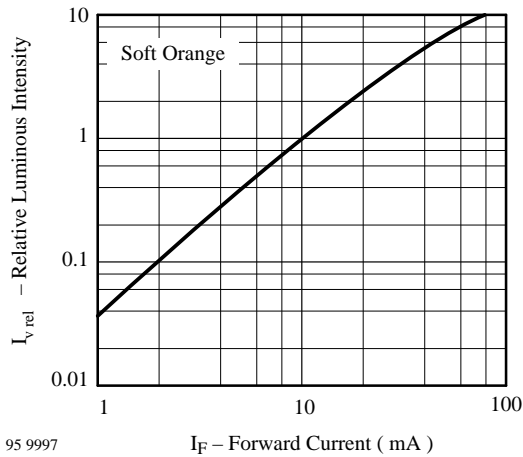
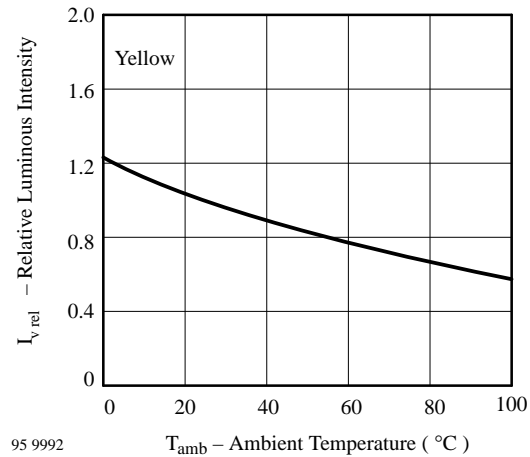


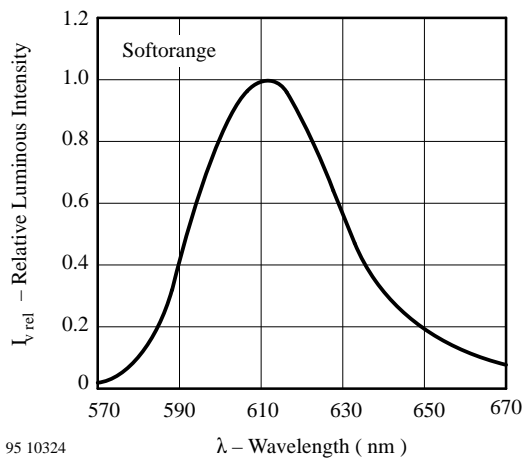
Figure 12. Rel. Lumin. Intensity vs. Forw. Current/Duty Cycle



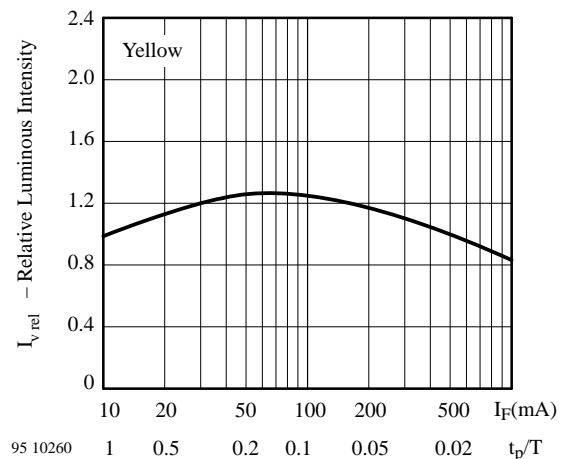
95 9997  $I_F$  – Forward Current ( mA )  
Figure 13. Relative Luminous Intensity vs. Forward Current



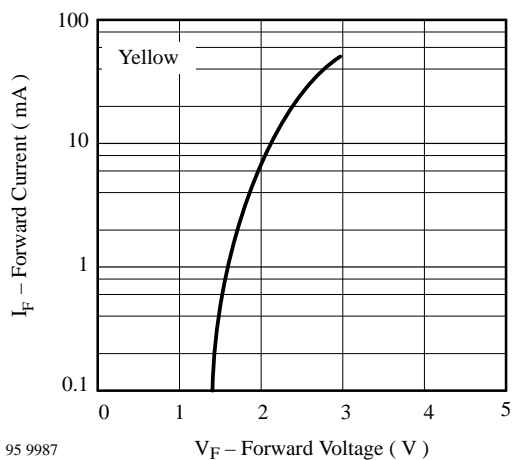
95 9992  $T_{amb}$  – Ambient Temperature ( °C )  
Figure 16. Rel. Luminous Intensity vs. Ambient Temperature



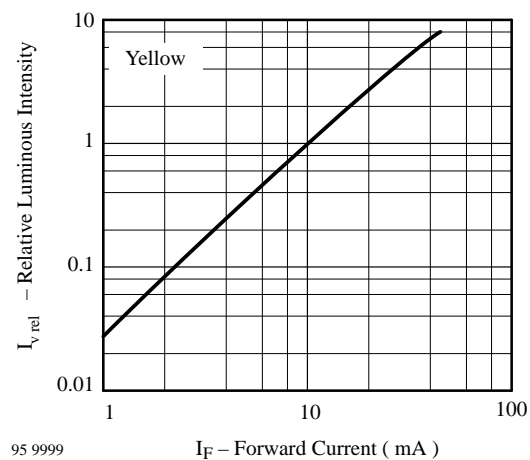
95 10324  $\lambda$  – Wavelength ( nm )  
Figure 14. Relative Luminous Intensity vs. Wavelength



95 10260  $I_F$ (mA)  $t_p/T$   
Figure 17. Rel. Lumin. Intensity vs. Forw. Current/Duty Cycle



95 9987  $V_F$  – Forward Voltage ( V )  
Figure 15. Forward Current vs. Forward Voltage



95 9999  $I_F$  – Forward Current ( mA )  
Figure 18. Relative Luminous Intensity vs. Forward Current

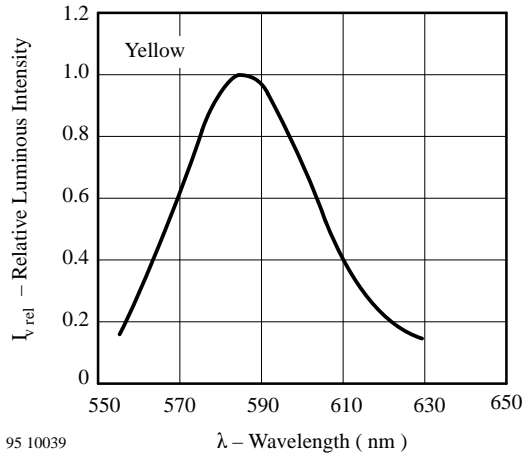


Figure 19. Relative Luminous Intensity vs. Wavelength

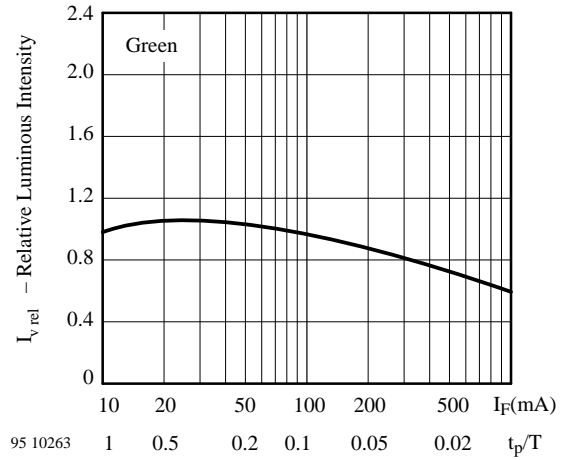


Figure 22. Rel. Lumin. Intensity vs. Forw. Current/Duty Cycle

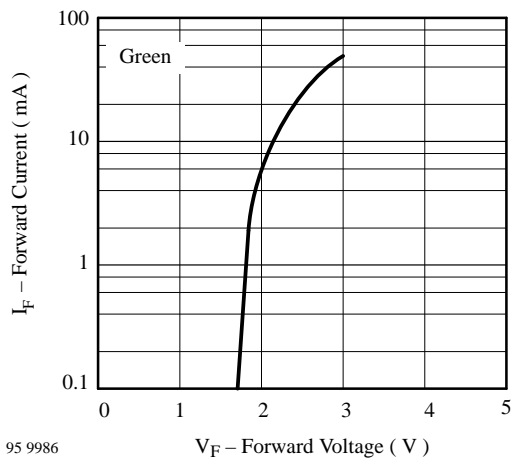


Figure 20. Forward Current vs. Forward Voltage

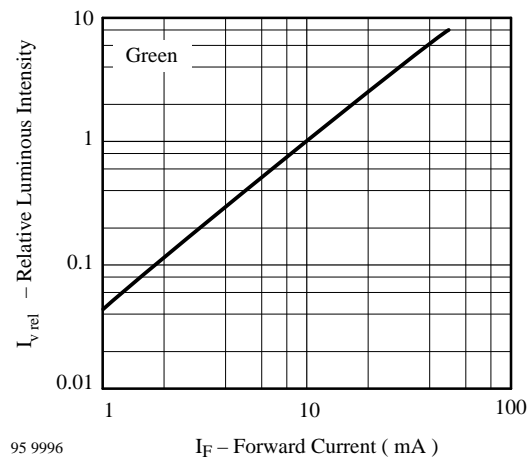


Figure 23. Relative Luminous Intensity vs. Forward Current

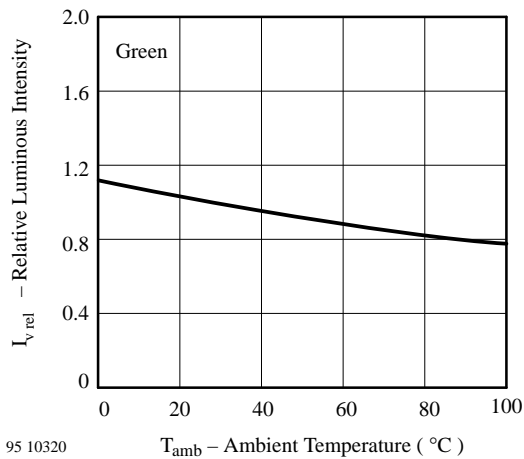


Figure 21. Rel. Luminous Intensity vs. Ambient Temperature

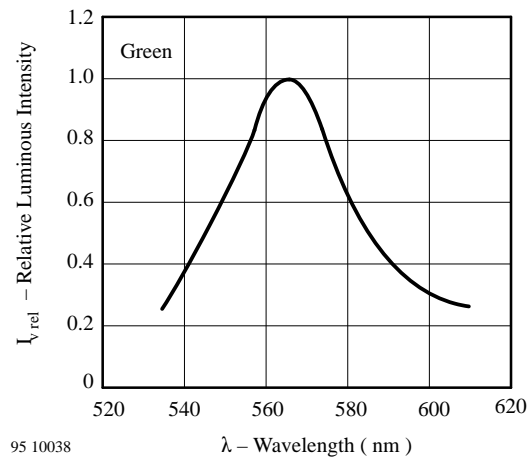


Figure 24. Relative Luminous Intensity vs. Wavelength

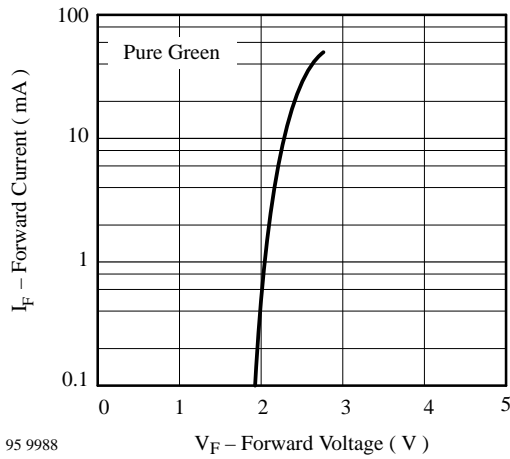


Figure 25. Forward Current vs. Forward Voltage

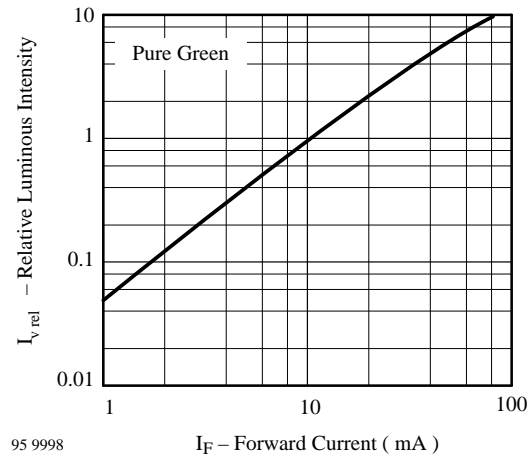


Figure 28. Relative Luminous Intensity vs. Forward Current

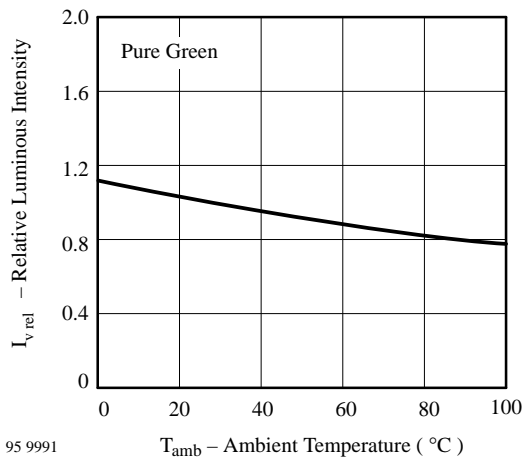


Figure 26. Rel. Luminous Intensity vs. Ambient Temperature

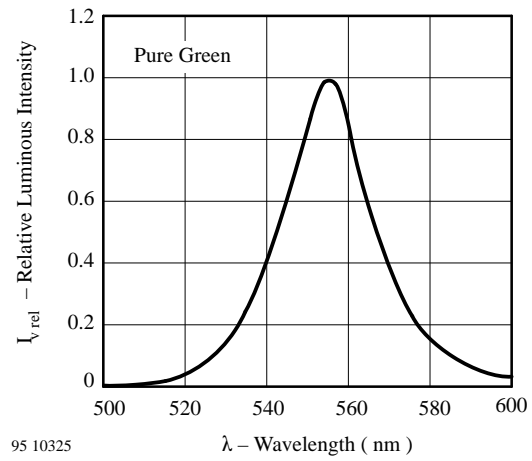


Figure 29. Relative Luminous Intensity vs. Wavelength

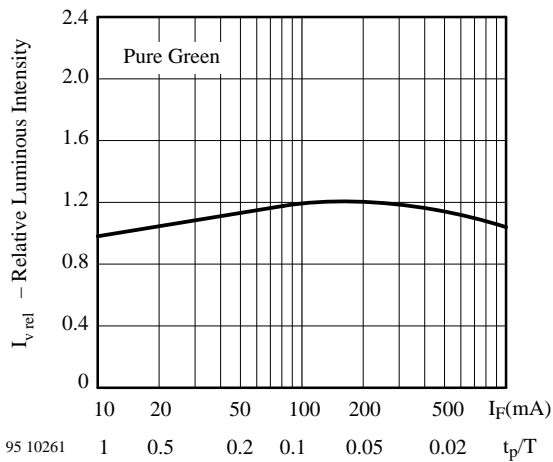
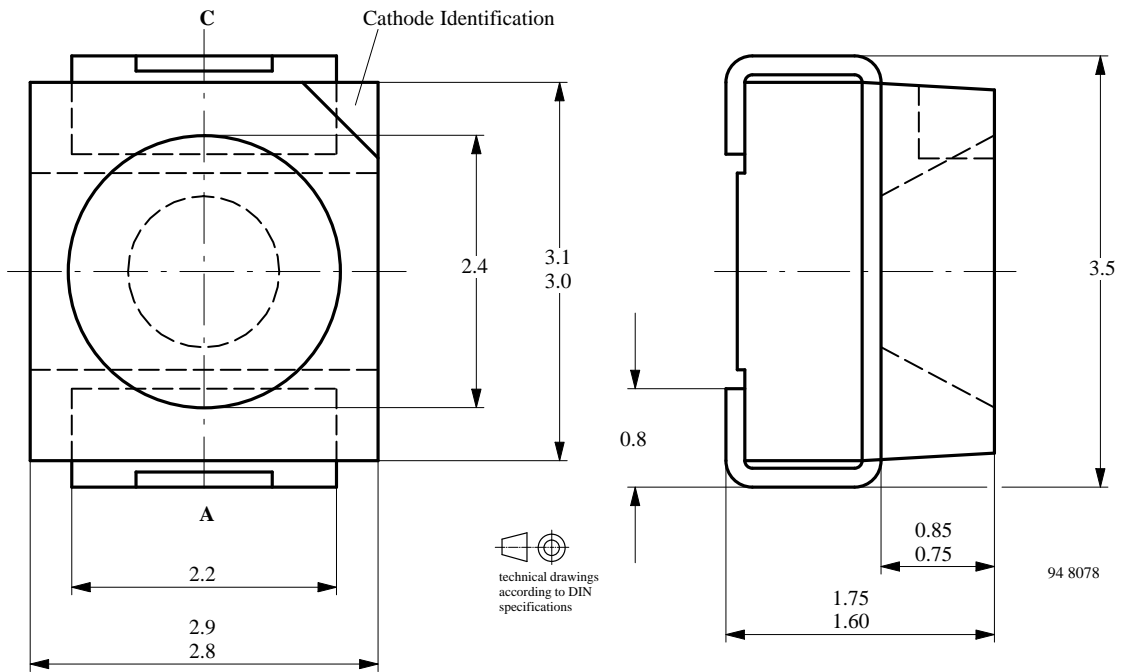


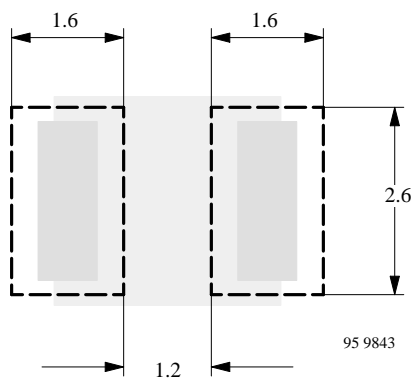
Figure 27. Rel. Lumin. Intensity vs. Forw. Current/Duty Cycle



## Dimensions in mm



## PCB Layout in mm



## Ozone Depleting Substances Policy Statement

It is the policy of **TEMIC TELEFUNKEN microelectronic GmbH** to

1. Meet all present and future national and international statutory requirements.
2. Regularly and continuously improve the performance of our products, processes, distribution and operating systems with respect to their impact on the health and safety of our employees and the public, as well as their impact on the environment.

It is particular concern to control or eliminate releases of those substances into the atmosphere which are known as ozone depleting substances (ODSs).

The Montreal Protocol (1987) and its London Amendments (1990) intend to severely restrict the use of ODSs and forbid their use within the next ten years. Various national and international initiatives are pressing for an earlier ban on these substances.

**TEMIC TELEFUNKEN microelectronic GmbH** semiconductor division has been able to use its policy of continuous improvements to eliminate the use of ODSs listed in the following documents.

1. Annex A, B and list of transitional substances of the Montreal Protocol and the London Amendments respectively
2. Class I and II ozone depleting substances in the Clean Air Act Amendments of 1990 by the Environmental Protection Agency (EPA) in the USA
3. Council Decision 88/540/EEC and 91/690/EEC Annex A, B and C (transitional substances) respectively.

**TEMIC** can certify that our semiconductors are not manufactured with ozone depleting substances and do not contain such substances.

**We reserve the right to make changes to improve technical design and may do so without further notice.**

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